

## 64K (8K x 8) Low-Voltage CMOS EPROM

### FEATURES

- Wide voltage range 3.0V to 5.5V
- High speed performance
  - 200 ns access time available at 3.0V
- CMOS Technology for low power consumption
  - 8 mA active current at 3.0V
  - 20 mA active current at 5.5V
  - 100  $\mu$ A standby current
- Factory programming available
- Auto-insertion-compatible plastic packages
- Auto ID aids automated programming
- Separate chip enable and output enable controls
- High speed "express" programming algorithm
- Organized 8K x 8: JEDEC standard pinouts
  - 28-pin Dual-in-line package
  - 32-pin PLCC Package
  - 28-pin SOIC package
  - Tape and reel
- Available for the following temperature ranges:
  - Commercial: 0°C to +70°C
  - Industrial: -40°C to +85°C

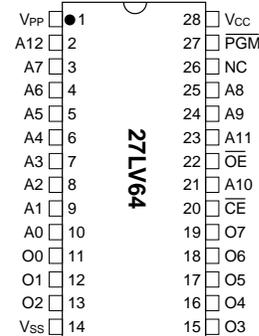
### DESCRIPTION

The Microchip Technology Inc. 27LV64 is a low-voltage (3.0 volt) CMOS EPROM designed for battery powered applications. The device is organized as 8K x 8 (8K-Byte) non-volatile memory product. The 27LV64 consumes only 8mA maximum of active current during a 3.0 volt read operation therefore improving battery performance. This device is designed for very low voltage applications where conventional 5.0 volt only EPROMs can not be used. Accessing individual bytes from an address transition or from power-up (chip enable pin going low) is accomplished in less than 200 ns at 3.0V. This device allows system designers the ability to use low voltage non-volatile memory with today's low voltage microprocessors and peripherals in battery powered applications.

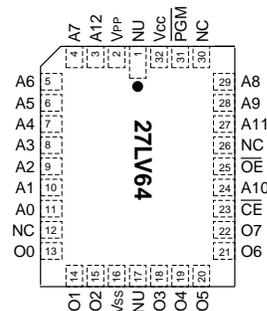
A complete family of packages is offered to provide the most flexibility in applications. For surface mount applications, PLCC or SOIC packaging is available. Tape and reel packaging is also available for PLCC or SOIC packages.

### PACKAGE TYPES

#### DIP/SOIC



#### PLCC



# 27LV64

## 1.0 ELECTRICAL CHARACTERISTICS

### 1.1 Maximum Ratings\*

VCC and input voltages w.r.t. VSS ..... -0.6V to + 7.25V  
 VPP voltage w.r.t. VSS during programming ..... -0.6V to +14V  
 Voltage on A9 w.r.t. VSS..... -0.6V to +13.5V  
 Output voltage w.r.t. VSS.....-0.6V to VCC +1.0V  
 Storage temperature ..... -65°C to +150°C  
 Ambient temp. with power applied..... -65°C to +125°C

\*Notice: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

TABLE 1-1: PIN FUNCTION TABLE

Name	Function
A0-A12	Address Inputs
$\overline{CE}$	Chip Enable
$\overline{OE}$	Output Enable
$\overline{PGM}$	Program Enable
VPP	Programming Voltage
O0 - O7	Data Output
VCC	+5V Or +3V Power Supply
VSS	Ground
NC	No Connection; No Internal Connections
NU	Not Used; No External Connection Is Allowed

TABLE 1-2: READ OPERATION DC CHARACTERISTICS

VCC = 3.0V to 5.5V unless otherwise specified Commercial: Tamb = 0°C to +70°C Industrial: Tamb = -40°C to +85°C							
Parameter	Part*	Status	Symbol	Min.	Max.	Units	Conditions
Input Voltages	all	Logic "1"	V <sub>IH</sub>	2.0	V <sub>CC</sub> +1	V	
		Logic "0"	V <sub>IL</sub>	-0.5	0.8	V	
Input Leakage	all	—	I <sub>LI</sub>	-10	10	μA	V <sub>IN</sub> = 0 to V <sub>CC</sub>
Output Voltages	all	Logic "1"	V <sub>OH</sub>	2.4	0.45	V	I <sub>OH</sub> = -400 μA I <sub>OL</sub> = 2.1 mA
		Logic "0"	V <sub>OL</sub>			V	
Output Leakage	all	—	I <sub>LO</sub>	-10	10	μA	V <sub>OUT</sub> = 0V to V <sub>CC</sub>
Input Capacitance	all	—	C <sub>IN</sub>	—	6	pF	V <sub>IN</sub> = 0V; Tamb = 25°C; f = 1 MHz
Output Capacitance	all	—	C <sub>OUT</sub>	—	12	pF	V <sub>OUT</sub> = 0V; Tamb = 25°C; f = 1 MHz
Power Supply Current, Active	C	TTL input	I <sub>CC1</sub>	—	20 @ 5.0V	mA	V <sub>CC</sub> = 5.5V; V <sub>PP</sub> = V <sub>CC</sub> f = 1 MHz; $\overline{OE} = \overline{CE} = V_{IL}$ ; I <sub>OUT</sub> = 0 mA; V <sub>IL</sub> = -0.1 to 0.8V; V <sub>IH</sub> = 2.0 to V <sub>CC</sub> ; Note 1
	I	TTL input	I <sub>CC2</sub>	—	8 @ 3.0V	mA	
					25 @ 5.0V	mA	
					10 @ 3.0V	mA	
Power Supply Current, Standby	C	TTL input	I <sub>CC(S)</sub>	—	1 @ 3.0V	mA	$\overline{CE} = V_{CC} \pm 0.2V$
	I	TTL input			2 @ 3.0V	mA	
	all	CMOS input			100 @ 3.0V	μA	

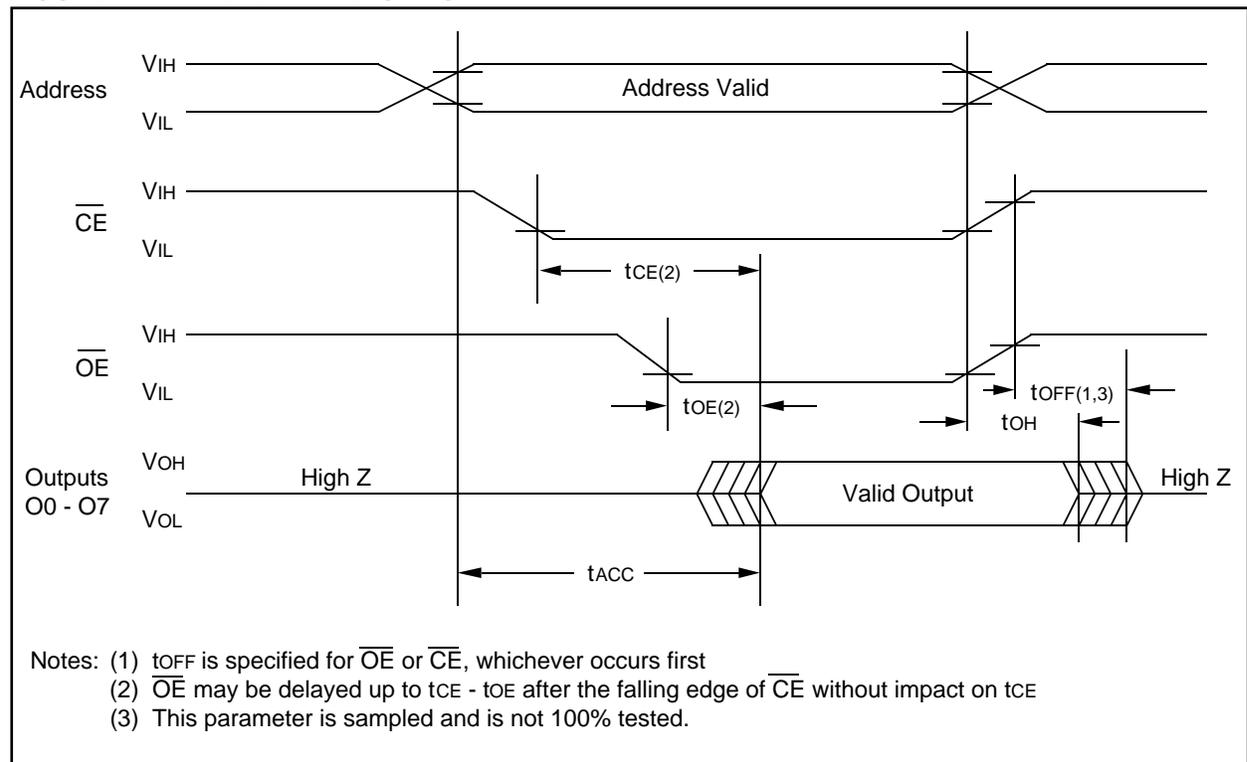
\* Parts: C=Commercial Temperature Range; I=Industrial Temperature Range

Note 1: Typical active current increases .5 mA per MHz up to operating frequency for all temperature ranges.

**TABLE 1-3: READ OPERATION AC CHARACTERISTICS**

Parameter	Sym	27LV64-20		27LV64-25		27LV64-30		Units	Conditions
		Min.	Max.	Min.	Max.	Min.	Max.		
		AC Testing Waveform: $V_{IH} = 2.4V$ and $V_{IL} = 0.45V$ ; $V_{OH} = 2.0V$ $V_{OL} = 0.8V$ Output Load: 1 TTL Load + 100 pF Input Rise and Fall Times: 10 ns Ambient Temperature: Commercial: $T_{amb} = 0^{\circ}C$ to $+70^{\circ}C$ Industrial: $T_{amb} = -40^{\circ}C$ to $+85^{\circ}C$							
Address to Output Delay	$t_{ACC}$	—	200	—	250	—	300	ns	$\overline{CE} = \overline{OE} = V_{IL}$
$\overline{CE}$ to Output Delay	$t_{CE}$	—	200	—	250	—	300	ns	$\overline{OE} = V_{IL}$
$\overline{OE}$ to Output Delay	$t_{OE}$	—	100	—	125	—	125	ns	$\overline{CE} = V_{IL}$
$\overline{CE}$ or $\overline{OE}$ to O/P High Impedance	$t_{OFF}$	0	50	0	50	0	50	ns	
Output Hold from Address $\overline{CE}$ or $\overline{OE}$ , whichever goes first	$t_{OH}$	0	—	0	—	0	—	ns	

**FIGURE 1-1: READ WAVEFORMS**



**TABLE 1-4: PROGRAMMING DC CHARACTERISTICS**

Ambient Temperature: Tamb = 25°C ± 5°C VCC = 6.5V ± 0.25V, VPP = VH = 13.0V ± 0.25V						
Parameter	Status	Symbol	Min.	Max.	Units	Conditions
Input Voltages	Logic"1"	VIH	2.0	VCC+1	V	
	Logic"0"	VIL	-0.1	0.8	V	
Input Leakage	—	ILI	-10	10	μA	VIN = 0V to VCC
Output Voltages	Logic"1"	VOH	2.4		V	IOH = -400 μA
	Logic"0"	VOL		0.45	V	IOL = 2.1 mA
VCC Current, program & verify	—	ICC2	—	20	mA	Note 1
VPP Current, program	—	I PP2	—	25	mA	Note 1
A9 Product Identification	—	VH	11.5	12.5	V	

Note 1: VCC must be applied simultaneously or before VPP and removed simultaneously or after VPP.

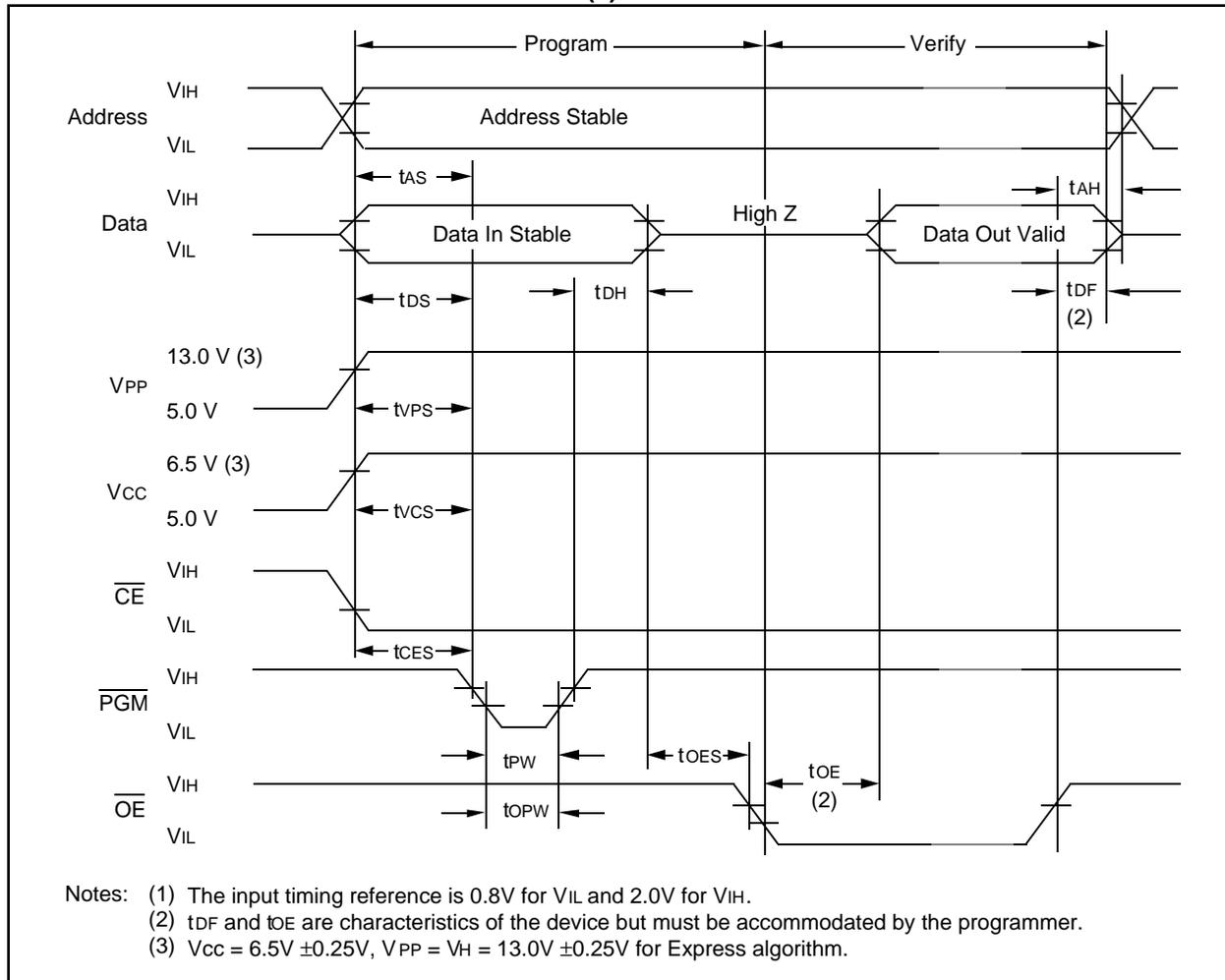
**TABLE 1-5: PROGRAMMING AC CHARACTERISTICS**

for Program, Program Verify and Program Inhibit Modes		AC Testing Waveform: VIH=2.4V and VIL=0.45V; VOH=2.0V; VOL=0.8V Ambient Temperature: Tamb=25°C ± 5°C VCC= 6.5V ± 0.25V, VPP = VH = 13.0V ± 0.25V				
Parameter	Symbol	Min.	Max.	Units	Remarks	
Address Set-Up Time	tAS	2	—	μs		
Data Set-Up Time	tDS	2	—	μs		
Data Hold Time	tDH	2	—	μs		
Address Hold Time	tAH	0	—	μs		
Float Delay (2)	tDF	0	130	ns		
VCC Set-Up Time	tVCS	2	—	μs		
Program Pulse Width (1)	tpw	95	105	μs	100 μs typical	
$\overline{CE}$ Set-Up Time	tCES	2	—	μs		
$\overline{OE}$ Set-Up Time	tOES	2	—	μs		
VPP Set-Up Time	tVPS	2	—	μs		
Data Valid from $\overline{OE}$	tOE		100	ns		

Note 1: For express algorithm, initial programming width tolerance is 100 μs ±5%.

Note 2: This parameter is only sampled and not 100% tested. Output float is defined as the point where data is no longer driven (see timing diagram).

**FIGURE 1-2: PROGRAMMING WAVEFORMS (1)**



**TABLE 1-6: MODES**

Operation Mode	$\overline{CE}$	$\overline{OE}$	PGM	VPP	A9	O0 - O7
Read	V <sub>IL</sub>	V <sub>IL</sub>	V <sub>IH</sub>	V <sub>CC</sub>	X	DOUT
Program	V <sub>IL</sub>	V <sub>IH</sub>	V <sub>IL</sub>	V <sub>H</sub>	X	DIN
Program Verify	V <sub>IL</sub>	V <sub>IL</sub>	V <sub>IH</sub>	V <sub>H</sub>	X	DOUT
Program Inhibit	V <sub>IH</sub>	X	X	V <sub>H</sub>	X	High Z
Standby	V <sub>IH</sub>	X	X	V <sub>CC</sub>	X	High Z
Output Disable	V <sub>IL</sub>	V <sub>IH</sub>	V <sub>IH</sub>	V <sub>CC</sub>	X	High Z
Identity	V <sub>IL</sub>	V <sub>IL</sub>	V <sub>IH</sub>	V <sub>CC</sub>	V <sub>H</sub>	Identity Code

X = Don't Care

## 1.2 Read Mode

(See Timing Diagrams and AC Characteristics)

Read Mode is accessed when

- the  $\overline{CE}$  pin is low to power up (enable) the chip
- the  $\overline{OE}$  pin is low to gate the data to the output pins

For Read operations, if the addresses are stable, the address access time ( $t_{ACC}$ ) is equal to the delay from  $\overline{CE}$  to output ( $t_{CE}$ ). Data is transferred to the output after a delay from the falling edge of  $\overline{OE}$  ( $t_{OE}$ ).

# 27LV64

## 1.3 Standby Mode

The standby mode is defined when the  $\overline{CE}$  pin is high ( $V_{IH}$ ) and a program mode is not defined.

When these conditions are met, the supply current will drop from 20 mA to 100  $\mu$ A.

## 1.4 Output Enable

This feature eliminates bus contention in microprocessor-based systems in which multiple devices may drive the bus. The outputs go into a high impedance state when the following condition is true:

- The  $\overline{OE}$  and  $\overline{PGM}$  pins are both high.

## 1.5 Erase Mode (U.V. Windowed Versions)

Windowed products offer the capability to erase the memory array. The memory matrix is erased to the all 1's state when exposed to ultraviolet light. To ensure complete erasure, a dose of 15 watt-second/cm<sup>2</sup> is required. This means that the device window must be placed within one inch and directly underneath an ultraviolet lamp with a wavelength of 2537 Angstroms, intensity of 12,000 $\mu$ W/cm<sup>2</sup> for approximately 20 minutes.

## 1.6 Programming Mode

The Express Algorithm has been developed to improve the programming throughput times in a production environment. Up to ten 100-microsecond pulses are applied until the byte is verified. No overprogramming is required. A flowchart of the express algorithm is shown in Figure 1-3.

Programming takes place when:

- VCC is brought to the proper voltage,
- VPP is brought to the proper  $V_H$  level,
- the  $\overline{CE}$  pin is low,
- the  $\overline{OE}$  pin is high, and
- the  $\overline{PGM}$  pin is low.

Since the erased state is "1" in the array, programming of "0" is required. The address to be programmed is set via pins A0-A12 and the data to be programmed is presented to pins O0-O7. When data and address are stable,  $\overline{OE}$  is high,  $\overline{CE}$  is low and a low-going pulse on the  $\overline{PGM}$  line programs that location.

## 1.7 Verify

After the array has been programmed it must be verified to ensure all the bits have been correctly programmed. This mode is entered when all the following conditions are met:

- VCC is at the proper level,
- VPP is at the proper  $V_H$  level,
- the  $\overline{CE}$  line is low,
- the  $\overline{PGM}$  line is high, and
- the  $\overline{OE}$  line is low.

## 1.8 Inhibit

When programming multiple devices in parallel with different data, only  $\overline{CE}$  or  $\overline{PGM}$  need be under separate control to each device. By pulsing the  $\overline{CE}$  or  $\overline{PGM}$  line low on a particular device in conjunction with the  $\overline{PGM}$  or  $\overline{CE}$  line low, that device will be programmed; all other devices with  $\overline{CE}$  or  $\overline{PGM}$  held high will not be programmed with the data, although address and data will be available on their input pins (i.e., when a high level is present on  $\overline{CE}$  or  $\overline{PGM}$ ); and the device is inhibited from programming.

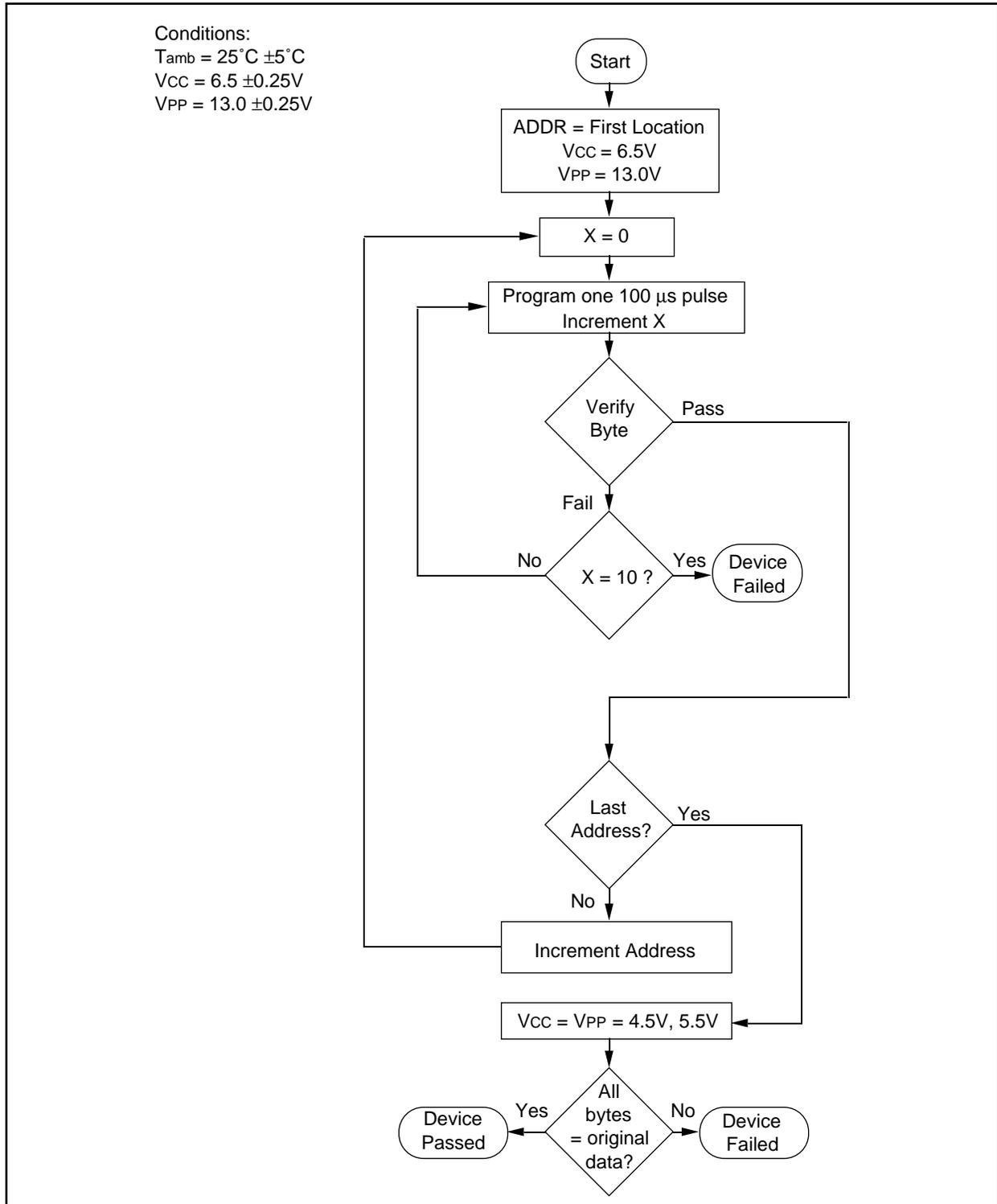
## 1.9 Identity Mode

In this mode specific data is output which identifies the manufacturer as Microchip Technology Inc. and device type. This mode is entered when Pin A9 is taken to  $V_H$  (11.5V to 12.5V). The  $\overline{CE}$  and  $\overline{OE}$  lines must be at  $V_{IL}$ . A0 is used to access any of the two non-erasable bytes whose data appears on O0 through O7.

Pin $\rightarrow$	Input	Output								
<b>Identity</b> $\downarrow$	<b>A0</b>	<b>0</b>	<b>H</b>							
Manufacturer	V <sub>IL</sub>	0	0	1	0	1	0	0	1	29
Device Type*	V <sub>IH</sub>	0	0	0	0	0	0	1	0	02

\* Code subject to change

FIGURE 1-3: PROGRAMMING EXPRESS ALGORITHM



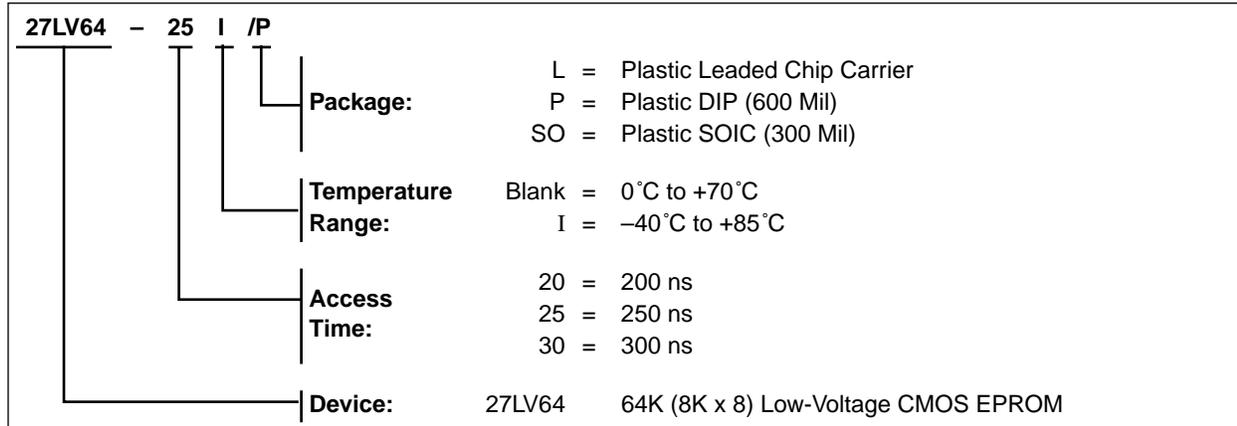
# 27LV64

---

NOTES:

## 27LV64 Product Identification System

To order or to obtain information, e.g., on pricing or delivery, please use the listed part numbers, and refer to the factory or the listed sales offices.



---

---

**Note the following details of the code protection feature on PICmicro® MCUs.**

- The PICmicro family meets the specifications contained in the Microchip Data Sheet.
- Microchip believes that its family of PICmicro microcontrollers is one of the most secure products of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the PICmicro microcontroller in a manner outside the operating specifications contained in the data sheet. The person doing so may be engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as “unbreakable”.
- Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our product.

If you have any further questions about this matter, please contact the local sales office nearest to you.

---

Information contained in this publication regarding device applications and the like is intended through suggestion only and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. No representation or warranty is given and no liability is assumed by Microchip Technology Incorporated with respect to the accuracy or use of such information, or infringement of patents or other intellectual property rights arising from such use or otherwise. Use of Microchip's products as critical components in life support systems is not authorized except with express written approval by Microchip. No licenses are conveyed, implicitly or otherwise, under any intellectual property rights.

#### **Trademarks**

The Microchip name and logo, the Microchip logo, FilterLab, KEELOQ, microID, MPLAB, PIC, PICmicro, PICMASTER, PICSTART, PRO MATE, SEEVAL and The Embedded Control Solutions Company are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

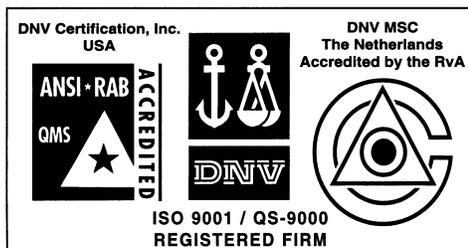
dsPIC, ECONOMONITOR, FanSense, FlexROM, fuzzyLAB, In-Circuit Serial Programming, ICSP, ICEPIC, microPort, Migratable Memory, MPASM, MPLIB, MPLINK, MPSIM, MXDEV, PICC, PICDEM, PICDEM.net, rPIC, Select Mode and Total Endurance are trademarks of Microchip Technology Incorporated in the U.S.A.

Serialized Quick Turn Programming (SQTP) is a service mark of Microchip Technology Incorporated in the U.S.A.

All other trademarks mentioned herein are property of their respective companies.

© 2002, Microchip Technology Incorporated, Printed in the U.S.A., All Rights Reserved.

 Printed on recycled paper.



*Microchip received QS-9000 quality system certification for its worldwide headquarters, design and wafer fabrication facilities in Chandler and Tempe, Arizona in July 1999. The Company's quality system processes and procedures are QS-9000 compliant for its PICmicro® 8-bit MCUs, KEELOQ® code hopping devices, Serial EEPROMs and microperipheral products. In addition, Microchip's quality system for the design and manufacture of development systems is ISO 9001 certified.*



# MICROCHIP

## WORLDWIDE SALES AND SERVICE

### AMERICAS

#### Corporate Office

2355 West Chandler Blvd.  
Chandler, AZ 85224-6199  
Tel: 480-792-7200 Fax: 480-792-7277  
Technical Support: 480-792-7627  
Web Address: <http://www.microchip.com>

#### Rocky Mountain

2355 West Chandler Blvd.  
Chandler, AZ 85224-6199  
Tel: 480-792-7966 Fax: 480-792-7456

#### Atlanta

500 Sugar Mill Road, Suite 200B  
Atlanta, GA 30350  
Tel: 770-640-0034 Fax: 770-640-0307

#### Boston

2 Lan Drive, Suite 120  
Westford, MA 01886  
Tel: 978-692-3848 Fax: 978-692-3821

#### Chicago

333 Pierce Road, Suite 180  
Itasca, IL 60143  
Tel: 630-285-0071 Fax: 630-285-0075

#### Dallas

4570 Westgrove Drive, Suite 160  
Addison, TX 75001  
Tel: 972-818-7423 Fax: 972-818-2924

#### Detroit

Tri-Atria Office Building  
32255 Northwestern Highway, Suite 190  
Farmington Hills, MI 48334  
Tel: 248-538-2250 Fax: 248-538-2260

#### Kokomo

2767 S. Albright Road  
Kokomo, Indiana 46902  
Tel: 765-864-8360 Fax: 765-864-8387

#### Los Angeles

18201 Von Karman, Suite 1090  
Irvine, CA 92612  
Tel: 949-263-1888 Fax: 949-263-1338

#### New York

150 Motor Parkway, Suite 202  
Hauppauge, NY 11788  
Tel: 631-273-5305 Fax: 631-273-5335

#### San Jose

Microchip Technology Inc.  
2107 North First Street, Suite 590  
San Jose, CA 95131  
Tel: 408-436-7950 Fax: 408-436-7955

#### Toronto

6285 Northam Drive, Suite 108  
Mississauga, Ontario L4V 1X5, Canada  
Tel: 905-673-0699 Fax: 905-673-6509

### ASIA/PACIFIC

#### Australia

Microchip Technology Australia Pty Ltd  
Suite 22, 41 Rawson Street  
Epping 2121, NSW  
Australia  
Tel: 61-2-9868-6733 Fax: 61-2-9868-6755

#### China - Beijing

Microchip Technology Consulting (Shanghai)  
Co., Ltd., Beijing Liaison Office  
Unit 915  
Bei Hai Wan Tai Bldg.  
No. 6 Chaoyangmen Beidajie  
Beijing, 100027, No. China  
Tel: 86-10-85282100 Fax: 86-10-85282104

#### China - Chengdu

Microchip Technology Consulting (Shanghai)  
Co., Ltd., Chengdu Liaison Office  
Rm. 2401, 24th Floor,  
Ming Xing Financial Tower  
No. 88 TIDU Street  
Chengdu 610016, China  
Tel: 86-28-6766200 Fax: 86-28-6766599

#### China - Fuzhou

Microchip Technology Consulting (Shanghai)  
Co., Ltd., Fuzhou Liaison Office  
Unit 28F, World Trade Plaza  
No. 71 Wusi Road  
Fuzhou 350001, China  
Tel: 86-591-7503506 Fax: 86-591-7503521

#### China - Shanghai

Microchip Technology Consulting (Shanghai)  
Co., Ltd.  
Room 701, Bldg. B  
Far East International Plaza  
No. 317 Xian Xia Road  
Shanghai, 200051  
Tel: 86-21-6275-5700 Fax: 86-21-6275-5060

#### China - Shenzhen

Microchip Technology Consulting (Shanghai)  
Co., Ltd., Shenzhen Liaison Office  
Rm. 1315, 13/F, Shenzhen Kerry Centre,  
Renminnan Lu  
Shenzhen 518001, China  
Tel: 86-755-2350361 Fax: 86-755-2366086

#### Hong Kong

Microchip Technology Hongkong Ltd.  
Unit 901-6, Tower 2, Metroplaza  
223 Hing Fong Road  
Kwai Fong, N.T., Hong Kong  
Tel: 852-2401-1200 Fax: 852-2401-3431

#### India

Microchip Technology Inc.  
India Liaison Office  
Divyasree Chambers  
1 Floor, Wing A (A3/A4)  
No. 11, O'Shaugnessey Road  
Bangalore, 560 025, India  
Tel: 91-80-2290061 Fax: 91-80-2290062

### Japan

Microchip Technology Japan K.K.  
Benex S-1 6F  
3-18-20, Shinyokohama  
Kohoku-Ku, Yokohama-shi  
Kanagawa, 222-0033, Japan  
Tel: 81-45-471- 6166 Fax: 81-45-471-6122

### Korea

Microchip Technology Korea  
168-1, Youngbo Bldg. 3 Floor  
Samsung-Dong, Kangnam-Ku  
Seoul, Korea 135-882  
Tel: 82-2-554-7200 Fax: 82-2-558-5934

### Singapore

Microchip Technology Singapore Pte Ltd.  
200 Middle Road  
#07-02 Prime Centre  
Singapore, 188980  
Tel: 65-334-8870 Fax: 65-334-8850

### Taiwan

Microchip Technology Taiwan  
11F-3, No. 207  
Tung Hua North Road  
Taipei, 105, Taiwan  
Tel: 886-2-2717-7175 Fax: 886-2-2545-0139

### EUROPE

#### Denmark

Microchip Technology Nordic ApS  
Regus Business Centre  
Lautrup høj 1-3  
Ballerup DK-2750 Denmark  
Tel: 45 4420 9895 Fax: 45 4420 9910

#### France

Microchip Technology SARL  
Parc d'Activite du Moulin de Massy  
43 Rue du Saule Trapu  
Batiment A - 1er Etage  
91300 Massy, France  
Tel: 33-1-69-53-63-20 Fax: 33-1-69-30-90-79

#### Germany

Microchip Technology GmbH  
Gustav-Heinemann Ring 125  
D-81739 Munich, Germany  
Tel: 49-89-627-144 0 Fax: 49-89-627-144-44

#### Italy

Microchip Technology SRL  
Centro Direzionale Colleoni  
Palazzo Taurus 1 V. Le Colleoni 1  
20041 Agrate Brianza  
Milan, Italy  
Tel: 39-039-65791-1 Fax: 39-039-6899883

#### United Kingdom

Arizona Microchip Technology Ltd.  
505 Eskdale Road  
Winnersh Triangle  
Wokingham  
Berkshire, England RG41 5TU  
Tel: 44 118 921 5869 Fax: 44-118 921-5820

01/18/02